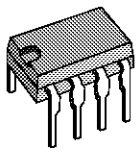
SGS-THOMSON MICROELECTRONICS

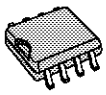
TEB1033
TEF1033-TEC1033

DUAL BIPOLAR OPERATIONAL AMPLIFIERS

- LOW DISTORTION RATIO
- LOW NOISE
- VERY LOW SUPPLY CURRENT
- LOW INPUT OFFSET CURRENT
- VERY LOW INPUT OFFSET VOLTAGE
- LARGE COMMON-MODE RANGE
- HIGH GAIN
- HIGH OUTPUT CURRENT
- GAIN-BANDWIDTH PRODUCT : 2.5MHz
- TEMPERATURE DRIFT : 2µV/°C
- LONG TERM STABILITY : 8µV/YEAR (for $T_{amb} \leq 50^{o}C$)



N
DIP8
(Plastic Package)



D
SO8
(Plastic Micropackage)

DESCRIPTION

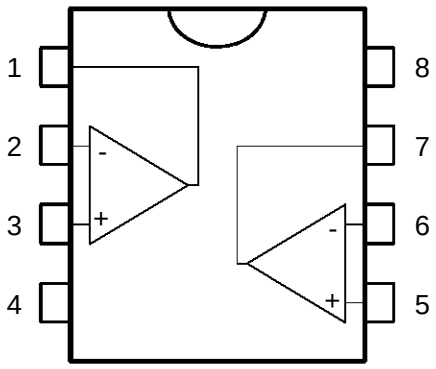
The TEB1033, TEF1033 and TEC1033 are high performance dual-operational amplifiers intended for active filter applications. The internal phase compensation allows stable operation as voltage follower in spite of their high gain-bandwidth products. The circuits present very stable electrical characteristics over the entire supply voltage range.

ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TEB1033	0°C, +70°C	•	•
TEF1033	–40°C, +105°C	•	•
TEC1033	–55°C, +125°C	•	•
Example : TEB1033N			

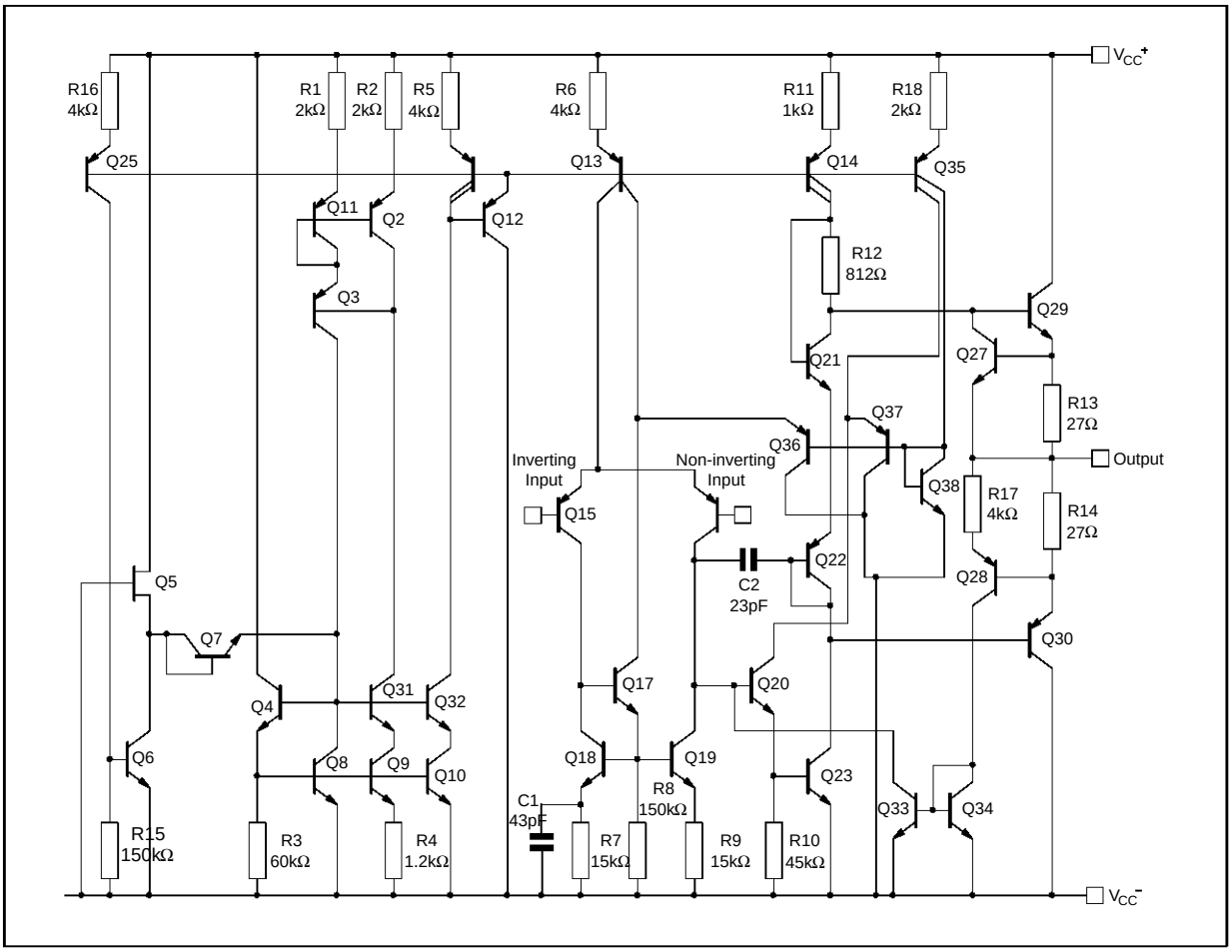
1033-01.TBL

PIN CONNECTIONS (top view)



1 - Output 1
2 - Inverting input 1
3 - Non-inverting input 1
4 - V_{CC}^{-}
5 - Non-inverting input 2
6 - Inverting input 2
7 - Output 2
8 - V_{CC}^{+}

BLOCK DIAGRAM (1/2 TEB1033)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		± 18	V
V_i	Input Voltage		± V_{CC}	V
V_{id}	Differential Input Voltage		± (V_{CC} –1)	V
P_{tot}	Power Dissipation	D suffix N suffix	400 665	mW
T_{oper}	Operating Free-air Temperature Range	TEB1033 TEF1033 TEC1033	0 to +70 –40 to +105 –55 to +125	°C
T_{stg}	Storage Temperature Range		–65 to +150	°C

1033-02.TBL

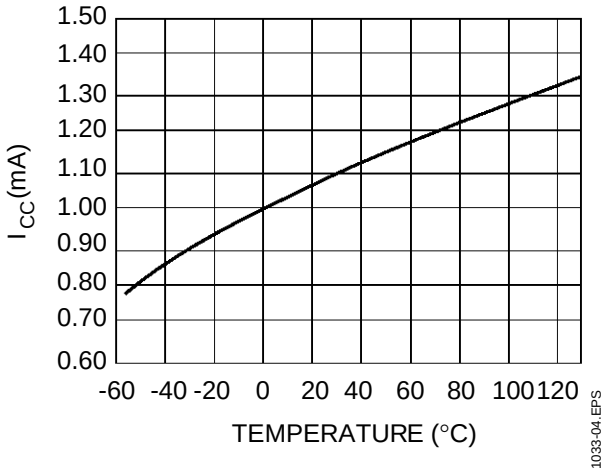
ELECTRICAL CHARACTERISTICS

V_{CC} = ±15V, T_{amb} = +25°C (unless otherwise specified)

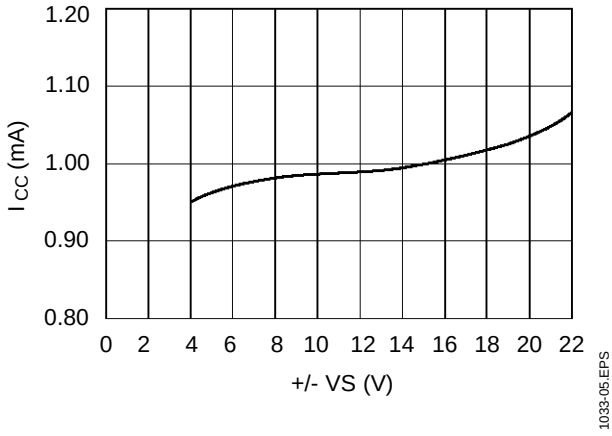
Symbol	Parameter	TEB 1033 TEF 1033 TEC 1033			Unit
		Min.	Typ.	Max.	
V_{io}	Input Offset Voltage ($R_S \leq 10k\Omega$) T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$		0.3	1 3	mV
DV_{io}	Input Offset Voltage Drift		2		µV/°C
I_{io}	Input Offset Current T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 40	nA
I_{ib}	Input Bias Current T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$		50	100 200	nA
A_{vd}	Large Signal Voltage Gain (R_L = 2kΩ, V_O = ±10V) T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$	80 40	120		V/mV
SVR	Supply Voltage Rejection Ratio (DV_{CC} from ±15V to ±4V) T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$	80 70	100		dB
I_{CC}	Supply Current, all Amp, no Load T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$		1	1.5 2	mA
V_{icm}	Input Common Mode Voltage Range T_{amb} = 25°C	±12			V
CMR	Common Mode Rejection Ratio ($R_S \leq 10k\Omega$, V_{ic} = ±10V) T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$	80 70	100		dB
I_{os}	Output Short-circuit Current T_{amb} = 25°C $T_{min.} \leq T_{amb} \leq T_{max.}$	10 10	23	40 40	mA
± V_{opp}	Output Voltage Swing T_{amb} = 25°C R_L = 2kΩ $T_{min.} \leq T_{amb} \leq T_{max.}$ R_L = 2kΩ V_{CC} = ±4V, R_L = 2kΩ, T_{amb} = 25°C V_{CC} = ±6V, R_L = 600Ω, T_{amb} = 25°C	13 12 2.8 4.6	14 3		V
SR	Slew-rate (V_I = ±10V, R_L = 2 kΩ, C_L = 100pF, T_{amb} = 25°C, unity gain)	0.6	1		V/µs
GBP	Gain Bandwidth Product (f = 100kHz, T_{amb} = 25°C, V_{in} = 10mV, R_L = 2kΩ, C_L = 100pF)	1.5	2		MHz
R_I	Input Resistance		1		MΩ
THD	Total Harmonic Distortion (f = 1kHz, A_v = 20dB, R_L = 2kΩ C_L = 100pF, T_{amb} = 25°C, V_o = $2V_{pp}$)		0.008	0.05	%
e_n	Equivalent Input Noise Voltage (f = 1kHz) R_S = 50Ω R_S = 1kΩ R_S = 10kΩ		8 10 18	15	$\frac{nV}{\sqrt{Hz}}$
V_{OPP}	Large Signal Voltage Swing R_L =10kΩ, f = 10kHz	26	28		V
Øm	Phase Margin		45		Degrees
V_{o1}/V_{o2}	Channel Separation	100	120		dB

1033-03.TBL

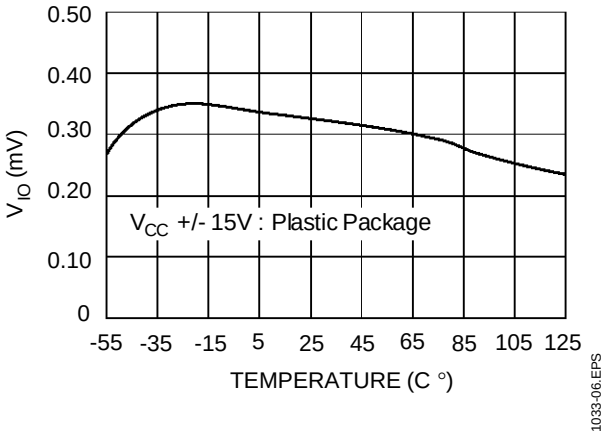
SUPPLY CURRENT VERSUS AMBIENT TEMPERATURE



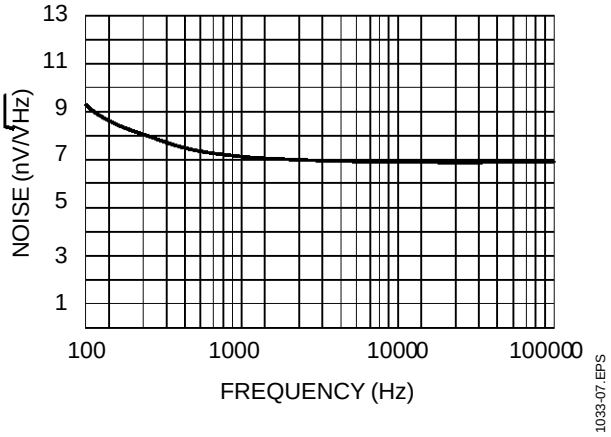
SUPPLY CURRENT VERSUS SUPPLY VOLTAGE



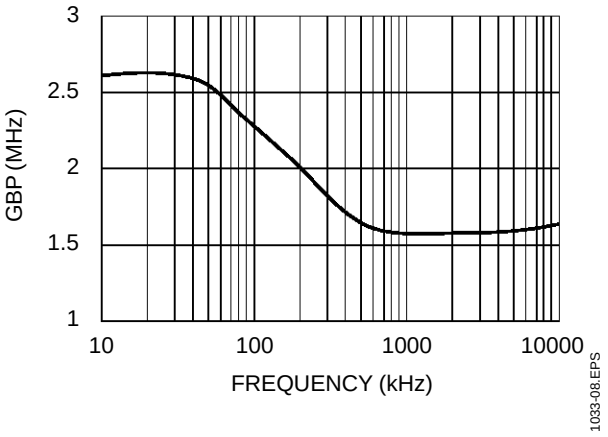
OFFSET VOLTAGE VERSUS AMBIENT TEMPERATURE



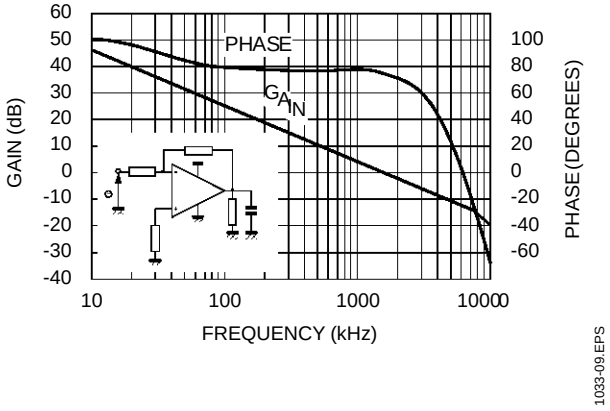
TOTAL INPUT NOISE VERSUS FREQUENCY



GAIN BANDWIDTH PRODUCT VERSUS FREQUENCY

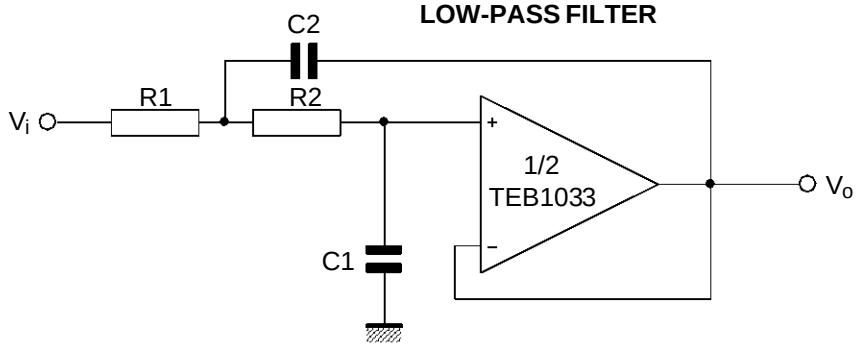


DODE PLOT



TYPICAL APPLICATION

LOW-PASS FILTER



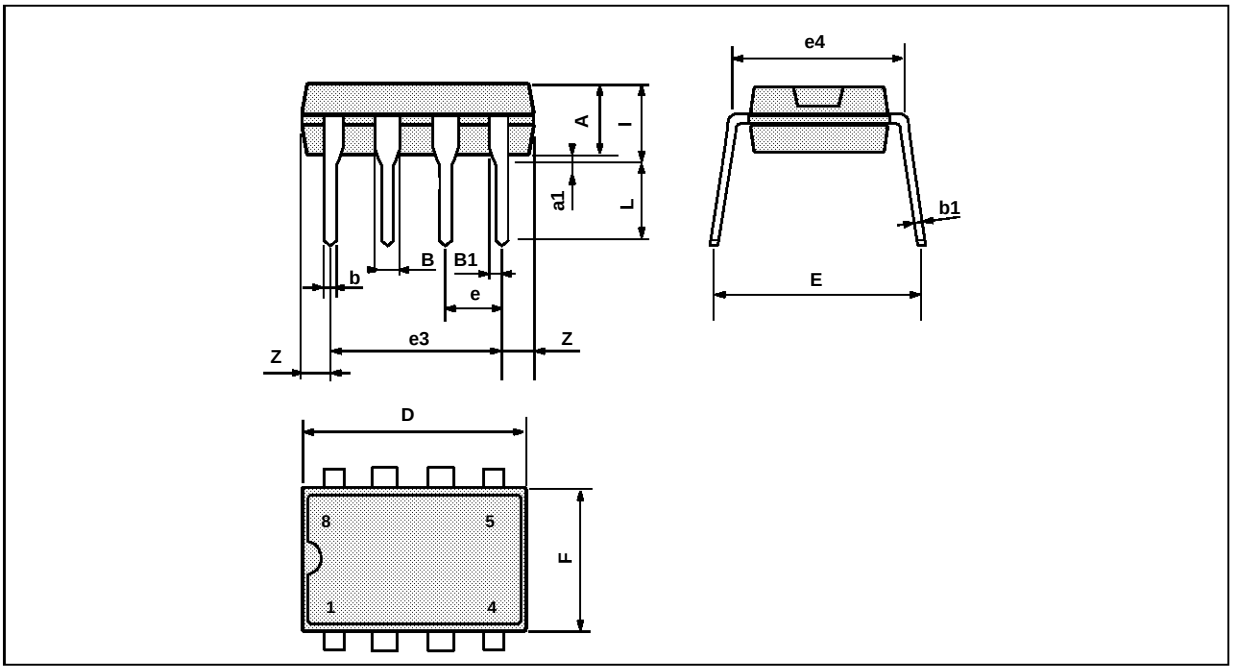
$$\frac{V_o}{V_i} = \frac{1}{1 + 2\xi \frac{S}{\omega_c} + \frac{S^2}{\omega_c^2}}$$

$\varpi_C = 2\pi f_C$, with f_C = cutt-off frequency
ξ = damping factor

1033-10.EPS

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC DIP OR CERDIP



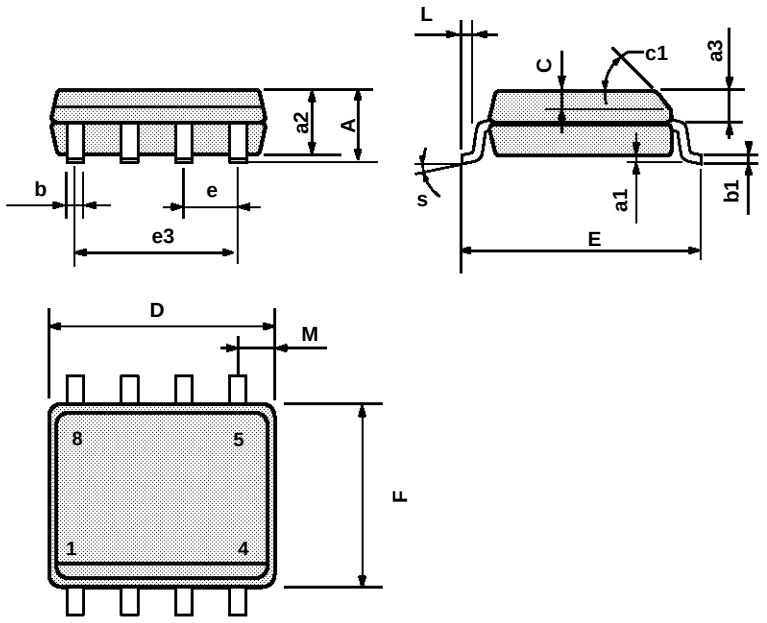
PM-DIP8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8.TBL

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



PM-SO8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45^o (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8^o (max.)					

SO8.TBL

ORDER CODE :